

650 V Gen 4 Power Silicon Carbide Schottky Diode, 8 A



LINKS TO ADDITIONAL RESOURCES



PRIMARY CHARACTERISTICS						
I _F 8 A						
V_R	650 V					
V _F at I _F at 25 °C, typ.	1.3 V					
T _J max.	175 °C					
I _R at V _R at 175 °C	41 μA typ.					
Q _C (V _R = 400 V)	22 nC					
Package	TO-220AC 2L					
Circuit configuration	Single					

FEATURES

Positive V_F temperature coefficient for easy paralleling



• Virtually no recovery tail and no switching losses

• 175 °C maximum operating junction temperature

HALOGEN

• AEC-Q101 qualified meets JESD 201 class 2 whisker test

• Solder bath temperature 275 °C maximum, 10 s per

JESD 22-B106
• Material categorization: for definitions of compliance

 Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION / APPLICATIONS

Wide band gap SiC based 650 V Schottky diode, designed for high performance and ruggedness.

Optimized for extreme high speed hard switching across a wide temperature range. This SiC diode is ideal for applications with high dl/d $_t$ such as high efficiency PFC and ultra-high frequency output rectifiers in AC/DC and DC/DC converters.

MECHANICAL DATA

Case: TO-220AC 2L

Molding compound meets UL 94 V-0 flammability rating Base P/NHM3 - halogen-free, RoHS-compliant, and

AEC-Q101 qualified

Terminals: matte tin plated leads, solderable per

J-STD-002 and JESD 22-B102

Mounting torque: 10 in-lbs maximum

MAXIMUM RATINGS (T _A = 25 °C unless otherwise specified)						
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Peak repetitive reverse voltage	V_{RRM}		650	V		
Continuous forward current	I _F ⁽¹⁾	T _C = 149 °C (DC)	8	Α		
Continuous forward current	I _F ⁽²⁾	T _C = 141 °C (DC)	8	Α		
DC blocking voltage	V_{DC}		650	V		
Repetitive peak forward current	I _{FRM}	T_C = 25 °C, f = 50 Hz, square wave, DC = 25 %	36	Α		
New yearstitive pools for your courses	I _{FSM}	$T_C = 25$ °C, $t_p = 10$ ms, half sine wave	51	Α		
Non-repetitive peak forward surge current		$T_C = 110$ °C, $t_p = 10$ ms, half sine wave	41			
	P _{tot} (1)	T _C = 25 °C	68	W A ² s		
Dawer discination		T _C = 110 °C	30			
Power dissipation	P _{tot} (2)	T _C = 25 °C	54			
		T _C = 110 °C	23			
I ² t value	∫i ² dt	T _C = 25 °C	13			
		T _C = 110 °C	8.4	A-8		
Operating junction and storage temperatures	T _J ⁽³⁾ , T _{Stg}		-55 to +175	°C		

Notes

- $^{(1)}$ Based on typical R_{th}
- (2) Based on maximum Rth
- $^{(3)}$ The heat generated must be less than the thermal conductivity from junction-to-ambient: $dP_D/dT_J < 1/R_{\theta JA}$



ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
		I _F = 8 A	-	1.3	1.5		
Forward voltage	V _F	I _F = 8 A, T _J = 150 °C	-	1.45	1.75	V	
		I _F = 8 A, T _J = 175 °C	-	1.55	-		
	I _R	$V_R = V_R$ rated	-	1.8	75	μΑ	
Reverse leakage current		V _R = V _R rated, T _J = 150 °C	-	21	145		
		V _R = V _R rated, T _J = 175 °C	-	41	-		
Total capacitance	С	V _R = 1 V, f = 1 MHz	-	365	-	nE	
		V _R = 400 V, f = 1 MHz	-	32	-	pF	
Total capacitive charge	Q _C	V _R = 400 V, f = 1 MHz	-	22	-	nC	

THERMAL AND MECHANICAL SPECIFICATIONS (T _A = 25 °C unless otherwise specified)							
PARAMETER	RAMETER SYMBOL TEST CONDITIONS MIN. TYP. MAX. UNITS						
Thermal resistance, junction-to-case	R _{thJC}		-	2.2	2.8	°C/W	
Marking device				4C08l	ET07T		

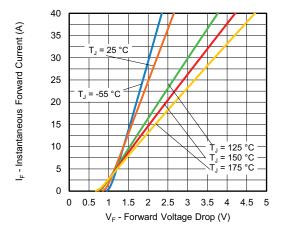


Fig. 1 - Typical Forward Voltage Drop Characteristics

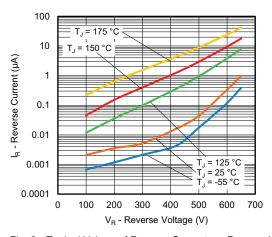


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

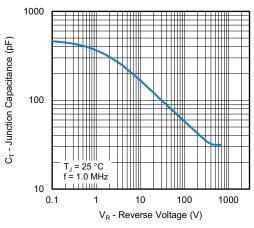


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

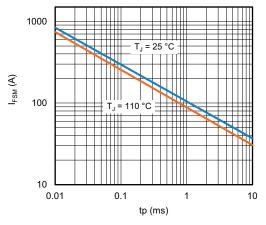


Fig. 4 - Non-Repetitive Peak Forward Surge Current vs. Pulse Duration (Square Wave)

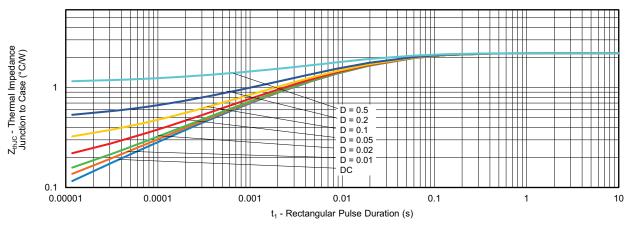


Fig. 5 - Typical Thermal Impedance Z_{thJC} Characteristics

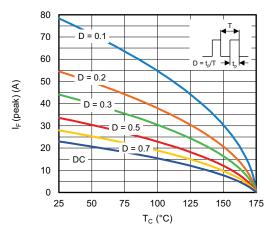


Fig. 6 - Peak Forward Current vs. Maximum Allowable Case Temperature

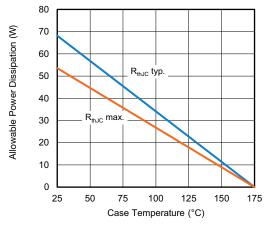


Fig. 7 - Forward Power Loss Characteristics

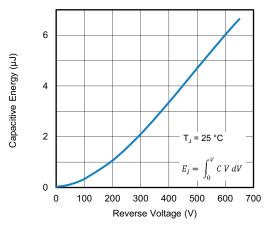


Fig. 8 - Typical Capacitive Energy vs. Reverse Voltage

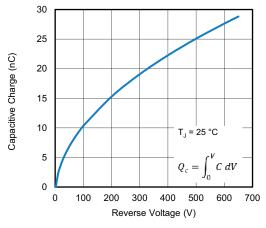
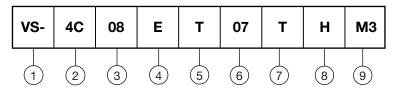


Fig. 9 - Typical Capacitive Charge vs. Reverse Voltage



ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

2 - 4C = SiC diode, Generation 4

Current rating (08 = 8 A)

4 - E = single diode

5 - Package TO-220

6 - Voltage rating: (07 = 650 V)

7 - T = true 2 pin

H = AEC-Q101 qualified

9 - Environmental digit:

M3 = halogen-free, RoHS-compliant, and termination lead (Pb)-free

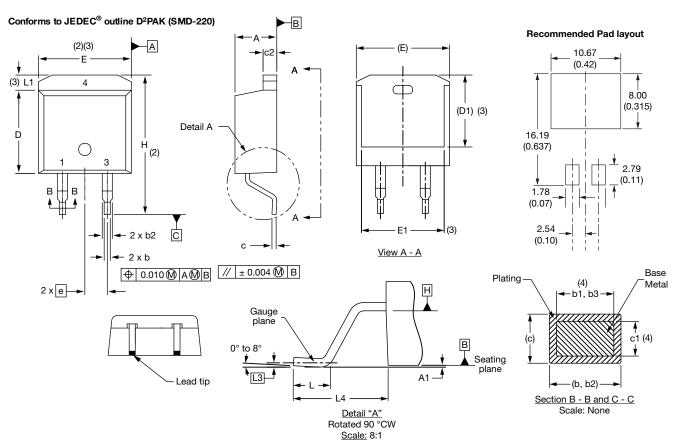
ORDERING INFORMATION						
PREFERRED P/N	UNIT WEIGHT	BASE QUANTITY	PACKAGING DESCRIPTION			
VS-4C08ET07THM3	2.0 g	50 / tube	Antistatic plastic tubes			

LINKS TO RELATED DOCUMENTS				
Dimensions	www.vishay.com/doc?96069			
Part marking information	www.vishay.com/doc?95391			



D²PAK 2L (TO-263AB 2L)

DIMENSIONS in millimeters and inches



SYMBOL	MILLIMETERS		INC	NOTES	
STWBOL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.06	4.83	0.160	0.190	
A1	0.00	0.254	0.000	0.010	
b	0.51	0.99	0.020	0.039	
b1	0.51	0.89	0.020	0.035	4
b2	1.14	1.78	0.045	0.070	
b3	1.14	1.73	0.045	0.068	4
С	0.38	0.74	0.015	0.029	
c1	0.38	0.58	0.015	0.023	4
c2	1.14	1.65	0.045	0.065	
D	8.51	9.65	0.335	0.380	2

SYMBOL	IVIILLIIVI	EIERS	INCHES		NOTES
STWIDUL	MIN.	MAX.	MIN.	MAX.	NOTES
D1	6.86	8.00	0.270	0.315	3
Е	9.65	10.67	0.380	0.420	2, 3
E1	7.90	8.80	0.311	0.346	3
е	2.54	2.54 BSC		BSC	
Н	14.61	15.88	0.575	0.625	
L	1.78	2.79	0.070	0.110	
L1	-	1.65	-	0.066	3
L3	0.25	0.25 BSC		BSC	
L4	4.78	5.28	0.188	0.208	

INICHES

NAUL LINAETEDO

Notes

- (1) Dimensioning and tolerancing per ASME Y14.5 M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- (3) Thermal pad contour optional within dimension E, L1, D1 and E1
- (4) Dimension b1 and c1 apply to base metal only
- (5) Datum A and B to be determined at datum plane H
- (6) Controlling dimension: inch
- (7) Outline conforms to JEDEC® outline TO-263AB



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